XU2M18AP20D

photo-electric sensor - XU2 - thru beam - high gain - Sn 50m - 12..24VDC - M12





Main

Range of product	OsiSense XU
Series name	Application material handling
Electronic sensor type	Photo-electric sensor
Sensor name	XU2
Sensor design	Cylindrical M18
Detection system	Thru beam
Material	Metal
Line of sight type	Axial
Type of output signal	Analogue Discrete
Supply circuit type	DC
Wiring technique	3-wire
Discrete output type	PNP
Discrete output function	1 NO
Analogue output range	420 mA
Electrical connection	1 male connector M12, 4 pins
Product specific application	-
Emission	Infrared thru beam
[Sn] nominal sensing distance	50 m thru beam

Complementary

Complementary		
Enclosure material	Nickel plated brass	
Lens material	PMMA	
Maximum sensing distance	70 m	
Output type	Solid state	
Add on output	With analogue output	
Add on input	Breaking test (transmitter)	
Status LED	1 LED (green) for supply on 1 LED (yellow) for operation	
[Us] rated supply voltage	1224 V DC with reverse polarity protection	
Supply voltage limits	1030 V DC	
Switching capacity in mA	<= 100 mA (overload and short-circuit protection)	
Switching frequency	<= 30 Hz	
Voltage drop	<= 1.5 V (closed state)	
Current consumption	<= 55 mA (no-load)	
Delay first up	<= 50 ms	
Delay response	<= 15 ms	
Delay recovery	<= 15 ms	
Setting-up	Sensitivity adjustment	
Diameter	18 mm	
Length	95 mm	
Product weight	0.155 kg	
Kit composition	Transmitter + receiver	

Environment



Product certifications	CE CSA UL
Ambient air temperature for operation	-2555 °C
Ambient air temperature for storage	-4070 °C
Vibration resistance	25 gn, amplitude = +/- 2 mm (f = 1055 Hz) conforming to IEC 60068-2-6
Shock resistance	30 gn (duration = 11 ms) conforming to IEC 60068-2-27
IP degree of protection	IP67 conforming to IEC 60529

Offer Sustainability

Sustainable offer status	Green Premium product
RoHS	Compliant - since 0924 - Schneider Electric declaration of conformity
Product environmental profile	Available
Product end of life instructions	Available

